

IN THE SPECIFICATION

Please amend the Abstract as indicated in the attached papers:

Please amend the paragraph beginning at page 28, last line, as follows:

The light emitting device of the present invention further has a blue phosphor and a green phosphor, together with the above-mentioned red phosphor, and a combination of these makes it possible to emit white light. For example, the blue phosphors include an inorganic phosphor such as ~~ZnS:Ag~~ ZnS:Ag, $\text{Sr}_5(\text{PO}_4)_3\text{Cl:Eu}$ or $\text{BaMgAl}_{10}\text{O}_{17}\text{:Eu}$. Further, the green phosphors include an inorganic phosphor such as ~~ZnS:Cu~~ ZnS:Cu, ZnS:CuAl , $\text{BaMgAl}_{10}\text{O}_{17}\text{:Eu}$ or Mn. In addition, the blue phosphors include a thulium complex, and the green phosphors include an organic phosphor such as a terbium complex. As the ligands of these complexes, there can be used known ligands, as well as the ligands of the Eu^{3+} complexes used in the present invention.

Please amend the paragraph beginning at page 30, line 10, as follows:

An example of the light emitting device of the present invention is shown in Fig. [[3]] 2. The light emitting device 10 shown in Fig. [[3]] 2 comprises a blanket 18, an outside cap 13 which covers an upper portion of the blanket 18 and is formed in a dome form, for example, from a light-permeable material such as glass, a mount lead 16b and an inner lead 16a which are attached to the blanket 18, an electric contact 19 which is attached to a lower portion of the blanket 18 and conductive to the mount lead 16b and the inner lead 16a, a semiconductor light emitting element 11 housed in a cup of an upper portion of the mount lead 16b, a sealing resin portion 17 such as an epoxy resin which is filled in the cup of the upper portion of the mount lead 16b to fix the semiconductor light emitting element 11, a phosphor layer 12 of a film in which a phosphor is mixed and dispersed in a binder resin and

which is coated on the inside of the outside cap 13, an ultraviolet absorbing layer 14b formed lying between the phosphor layer 12 and the outside cap 13, a conductive wire 15a which makes the inner lead 16a and the semiconductor light emitting element 11 conductive to each other, and a conductive wire 15b which makes the semiconductor light emitting element 11 and the mount lead 16b conductive to each other. The inside of the outside cap 13 is in vacuum or filled with an inert gas 14a such as nitrogen gas or argon gas.

Please amend the Abstract as shown in the marked-up and clean copy on the attached pages: